NSN 5961-01-374-5526

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-5526 **Inclosure Material:** Plastic **Overall Length:** 2.895 inches **Overall Height:** 0.700 inches **Overall Width:** 0.920 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon single semiconductor device diode Voltage Rating In Volts Per Characteristic: 36.0 breakdown voltage, instantaneous single semiconductor device diode **Current Rating Per Characteristic:** 300.00 amperes collector current, dc preset single semiconductor device diode **Power Rating Per Characteristic:** 10.0 watts any acceptable preset single semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 87990-755002b9706 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No